



Package Style: QFN, 16-pin, 3mmx3mmx0.5mm

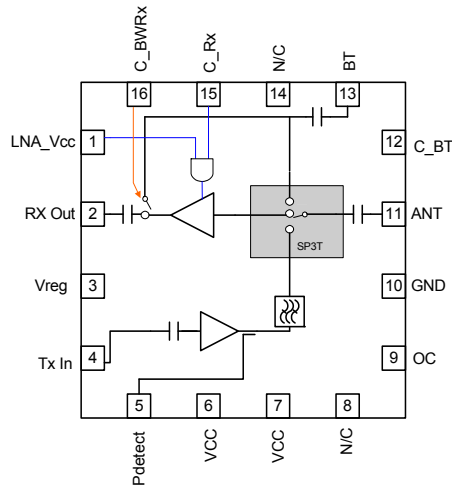


Features

- Integrated 2.4GHz to 2.5GHz b/g/n Amplifier, LNA, SP3T Switch, and Power Detector Coupler
- Single Supply Voltage 3.0V to 4.8V
- P_{OUT} = 19.5dBm, 11g, OFDM at <3.3% EVM, 22dBm 11b Meeting 11b Spectral Mask
- Low Height Package, Suited for SiP and CoB Designs

Applications

- Cellular handsets
- Mobile devices
- Tablets
- Consumer electronics
- Gaming
- Netbooks/Notebooks
- TV/monitors/video
- SmartEnergy



Functional Block Diagram

Product Description

The RF5755 provides a complete integrated solution in a single Front End Module (FEM) for WiFi 802.11b/g/n and *Bluetooth*® systems. The ultra small form factor and integrated matching greatly reduces the number of external components and layout area in the customer application. This simplifies the total Front End solution by reducing the bill of materials, system footprint, and manufacturability cost. The RF5755 integrates a 2.4GHz Power Amplifier (PA), Low Noise Amplifier (LNA), power detector coupler for improved accuracy, and some filtering for harmonic rejection. The RF5755 is capable of receiving WiFi and *Bluetooth*® simultaneously. The device is provided in a 3mmx3mmx0.5mm, 16-pin package. This module meets or exceeds the RF Front End needs of IEEE 802.11b/g/n WiFi RF systems.

Ordering Information

RF5755SQ	Standard 25 piece bag
RF5755SR	Standard 100 piece reel
RF5755TR7	Standard 2500 piece reel
RF5755PCK-410	Fully Assembled Evaluation Board with 5 loose sample pieces

Optimum Technology Matching® Applied

<input type="checkbox"/> GaAs HBT	<input type="checkbox"/> SiGe BiCMOS	<input checked="" type="checkbox"/> GaAs pHEMT	<input type="checkbox"/> GaN HEMT
<input type="checkbox"/> GaAs MESFET	<input type="checkbox"/> Si BiCMOS	<input type="checkbox"/> Si CMOS	<input type="checkbox"/> RF MEMS
<input checked="" type="checkbox"/> InGaP HBT	<input type="checkbox"/> SiGe HBT	<input type="checkbox"/> Si BJT	<input type="checkbox"/> LDMOS

Absolute Maximum Ratings

Parameter	Rating	Unit
DC Supply Voltage (Continuous with No Damage)	5.4	V
DC Supply Current	500	mA
Full Specification Temp Range (Full Spec. Compliant)	-10 to +70	°C
Extreme Operating (Reduced Performance)	-40 to -10 +70 to +85	°C
Storage Temperature	-40 to +150	°C
Antenna Port Nominal Impedance	50	Ω
Maximum Tx Input Power into 50 Ω Load for 11b/g/n (No Damage)	0	dBm
Maximum Rx Input Power (No Damage)	0	dBm
Moisture Sensitivity	MSL2	



Caution! ESD sensitive device.

Exceeding any one or a combination of the Absolute Maximum Rating conditions may cause permanent damage to the device. Extended application of Absolute Maximum Rating conditions to the device may reduce device reliability. Specified typical performance or functional operation of the device under Absolute Maximum Rating conditions is not implied.

RoHS status based on EUDirective2002/95/EC (at time of this document revision).

The information in this publication is believed to be accurate and reliable. However, no responsibility is assumed by RF Micro Devices, Inc. ("RFMD") for its use, nor for any infringement of patents, or other rights of third parties, resulting from its use. No license is granted by implication or otherwise under any patent or patent rights of RFMD. RFMD reserves the right to change component circuitry, recommended application circuitry and specifications at any time without prior notice.

Parameter	Specification			Unit	Condition
	Min.	Typ.	Max.		
2.4GHz Transmit Parameters					
Compliance					IEEE802.11b, IEEE802.11g, FCC CFG 15.247, .205,.209, EN, and JDEC
Nominal Conditions					Specifications must be met across V _{CC} , V _{REG} , and Temperature; unless otherwise specified.
Frequency	2.4		2.5	GHz	
Power Supply	3.0	3.3	4.2	V	PA nominal voltage supply (V _{CC})
V _{REG} Voltage					
ON	3.0	3.1	3.2	V	PA in “ON” state
OFF		0.00	0.20	V	PA in “OFF” state
Output Power					
11g	18	18.5		dBm	54Mbps, OFDM 54Mbps, V _{CC} ≥3.0V
	19	19.5		dBm	54Mbps, OFDM 54Mbps, V _{CC} ≥3.3V
11b	20	22		dBm	11Mbps, CCK, V _{CC} ≥3.0V
EVM		3.3	4.0	%	P _{OUT(g)} = Rated Output Power, 54Mbps OFDM, 50Ω, see note 1
Adjacent Channel Power					P _{OUT(b)} =20dBm 1Mbps CCK, note 2
ACP1		-36	-33	dBc	V _{CC} ≥3.3V, meeting 11b spectral mask requirements
ACP2		-56	-51	dBc	
Gain	26	30	34	dB	
Gain Variation Slope					At rated power and a given supply voltage, room temp
Range	3.0		4.2	V	
V _{CC} (Average)			0.5	dB/V	
V _{CC} (Instantaneous)			1	dB/V	
Frequency	-0.5		+0.5	dB	2.4GHz to 2.5GHz
Over Temperature	-1.5		+1.5	dB	
Typical Input Power					
11g		-9		dBm	
11b		-5		dBm	

Parameter	Specification			Unit	Condition
	Min.	Typ.	Max.		
2.4GHz Transmit Parameters, cont.					
Power Detect					
Power Range	0		23	dBm	
Voltage Range	0.1		1.5	V	
Resistance		10		kΩ	
Capacitance			10	pF	
Sensitivity					
0 < P _{OUT} < 6 dBm	3			mV/dB	
6 < P _{OUT} < 23 dBm	8		350	mV/dB	
Current Consumption					V _{CC} = 3.3V, V _{REG} = 3.1V, T = 25 °C.
I _{CC}		170	200	mA	RF P _{OUT} = 18.5 dBm, 11g, 50Ω
		220	250	mA	RF P _{OUT} = 20 dBm, 11b, 50Ω
Quiescent Current		90		mA	RF = “OFF”
I _{REG}			3	mA	V _{REG} > 3.0V
V _{CC} Leakage Current		2	10	μA	V _{CC} = 4.8V, V _{REG} = C_BT = C_RX = C_BWRx ≤ 0.2V
Input Port Impedance		50		Ω	
Input Port Return Loss	10	15		dB	
Ruggedness					No Damage Conditions: max operating voltage, max input power, max temperature
Output VSWR			10:1		
Input Power			-5	dBm	
Stability					PA must be stable (no spurs above -43 dBm) from 0 to 20 dBm, All phase angles, no spurious or oscillations
Output VSWR	6:1				
Out-of-Band Emissions 2310 MHz to 2390 MHz and 2483.5 MHz to 2500 MHz			-41.25	dBm/MHz	P _{OUT} = 16.5 dBm, 54 Mbps OFDM Modulation, 64 QAM, RBW = 1 MHz, VBW = 100 kHz, V _{CC} = 3.3V, V _{REG} = 3.1V
			-43	dBm/MHz	P _{OUT} = 20.5 dBm, 11 Mbps CCK Modulation, RBW = 1 MHz, VBW = 100 kHz, V _{CC} = 3.3V, V _{REG} = 3.1V
Thermal Resistance		20		°C/W	V _{CC} = 4.8, V _{REG} = 3.2, P _{OUT} = 20 dBm, T _{REF} = 85 °C
Harmonics					11b modulation, 1 Mbps, BW = 1 MHz, P _{OUT} = 20 dBm
Second			-23	dBm	4.80 GHz to 5.00 GHz
Third			-20	dBm	7.20 GHz to 7.50 GHz
Turn-on/off Time		0.5	1.0	μS	Output stable to within 90% of final gain, Note 1
2.4GHz Receive Parameters					
Compliance					IEEE802.11b, IEEE802.11g, FCC CFG 15.247, .205, .209, EN, and JDEC
Frequency	2.4		2.5	GHz	
LNA Voltage Supply (LNA V _{CC})	3.0	3.3	4.2	V	LNA V _{CC} tied to V _{BATT} at all times
LNA Current		10	20	mA	LNA in “ON” state
	0		5	μA	LNA in “OFF” state (C_RX = low, LNA V _{CC} = ON)
LNA Input P1dB	-7			dBm	
Gain					
WiFi Rx Gain	16	18	20	dB	WiFi Rx mode
Simultaneous WiFi/BT Rx Mode	11	13	15	dB	WiFi Rx/BT Mode, LNA “ON”

Parameter	Specification			Unit	Condition
	Min.	Typ.	Max.		
2.4GHz Receive Parameters, cont.					
Noise Figure					V _{CC} ≥3.3V, including switch
WiFi Rx		2.1	3.5	dB	WiFi Rx mode (LNA “ON”)
Simultaneous WiFi/BT Rx Mode		3	4	dB	WiFi Rx/BT Mode (LNA “ON”)
Passband Ripple	-0.2		+0.2	dB	WiFi Rx Mode
	-0.5		+0.5	dB	WiFi Rx/BT Mode
WiFi Rx Port Return Loss	9.6			dB	Over temp and nominal bias conditions (V _{CC} =3.3V)
	5	7		dB	Switch in WiFi Rx/Bluetooth Mode
WiFi Rx Port Impedance		50		Ω	No external matching
Bluetooth Parameters					
Frequency	2.4		2.5	GHz	
Insertion Gain/Loss					
BT Tx/Rx only Loss		1.2	1.5	dB	Bluetooth mode
BT Rx* Gain	11	13	15	dB	WiFi Rx/BT Mode, LNA “ON”
Passband Ripple	-0.2		+0.2	dB	Bluetooth mode
	-0.5		+0.5	dB	WiFi Rx/BT mode
Bluetooth Port Return Loss	9.6			dB	Switch in Bluetooth Mode
	7			dB	Switch in WiFi Rx/Bluetooth Mode
Input P1dB	27	30		dBm	Over Temp, C_BT=3.3V to 3.6V
Other Requirements					
Antenna Port Impedance					
Output		50		Ω	
Return Loss		10		dB	
Isolation					
Antenna to Receive	20			dB	In BT Mode (measured from ANT to Rx port)
Antenna to Bluetooth®	20			dB	In Tx Mode (measured from ANT to BT port)
Antenna to Receive	20			dB	In Tx Mode (measured from ANT to Rx port)
Switch Control Voltage					C Rx, C BT, and C BW Rx control lines
Low		0	0.2	V	Switch is in the low state (L)
High	1.7		3.6	V	Switch is in the high state (H)
Switch Control Current		2	10	μA	Per control line (C_BT, C_BWRX)
C_Rx Current			100	μA	Over V _{CC} , Frequency and Temperature.
Switch Control Speed			100	nsec	
Switch P1dB		28		dBm	
ESD					
Human Body Model	500			V	EIA/JESD22-114A RF pins
	1000			V	EIA/JESD22-114A DC pins
Charge Device Model	500			V	JESD22-C101C all pins

Note 1: The PA module must operate with gated bias voltage input at 1% to 99% duty cycle.

Note 2: The output power for channels 1 and 11 may be reduced to meet FCC restricted band requirements.

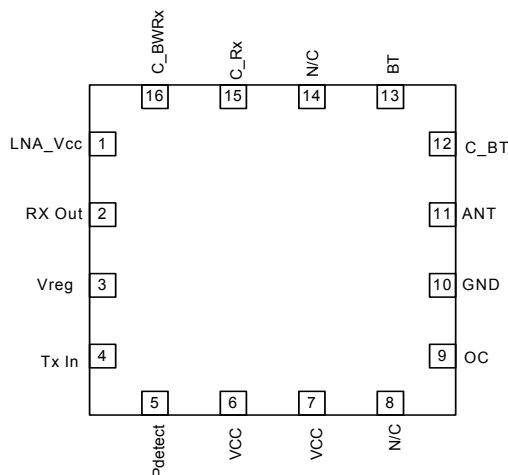
Switch Control Logic

Mode	V _{REG}	C Rx	C BT	C BWRx
Standby	L	L	L	L
WiFi Tx	H	L	L	L
WiFi Rx	L	H	L	L
WiFi Rx/BT*	L	H	L	H
BT Rx	L	L	H	L
BT Tx	L	L	H	L

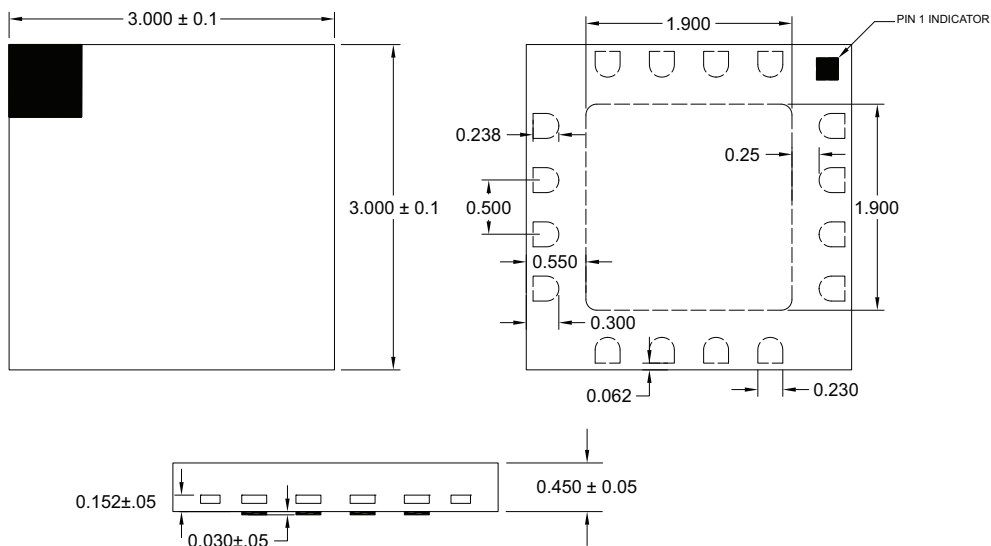
*The FEM can be placed in receive WiFi and *Bluetooth*® modes simultaneously with increased insertion loss.

Pin	Function	Description
1	LNA VDD	Voltage supply for the LNA.
2	RX OUT	Receive port for 802.11b/g band. Internally matched to 50Ω. DC block provided.
3	VREG	Regulated voltage for the bias control circuit, and the Tx control port of the SP3T which is also tied to this pin. An external bypass capacitor may be needed on the V _{REG} line for decoupling purposes.
4	TX	RF input for the 802.11b/g PA. Input is matched to 50Ω and DC block is provided.
5	PDETECT	Power detector voltage for Tx section. PDET voltage varies with output power. May need external decoupling capacitor for noise bypassing. May need external circuitry to bring output voltage to desired level.
6	VCC	Supply voltage for the PA.
7	VCC	Supply voltage for the PA.
8	N/C	No connect.
9	OC	Open Circuit.
10	GND	Ground.
11	ANT	Port matched to 50Ω and is DC blocked internally.
12	C_BT	Bluetooth® switch control pin. See truth table for proper level.
13	BT	RF bidirectional port for Bluetooth®. Input is matched to 50Ω and DC block is provided.
14	N/C	No connect.
15	C RX	Receive switch control pin. See switch truth table for proper level.
16	C_BWRX	SPST switch control pin. (Simultaneous WiFi and BT receive.) See truth table for proper level.

Pin Out



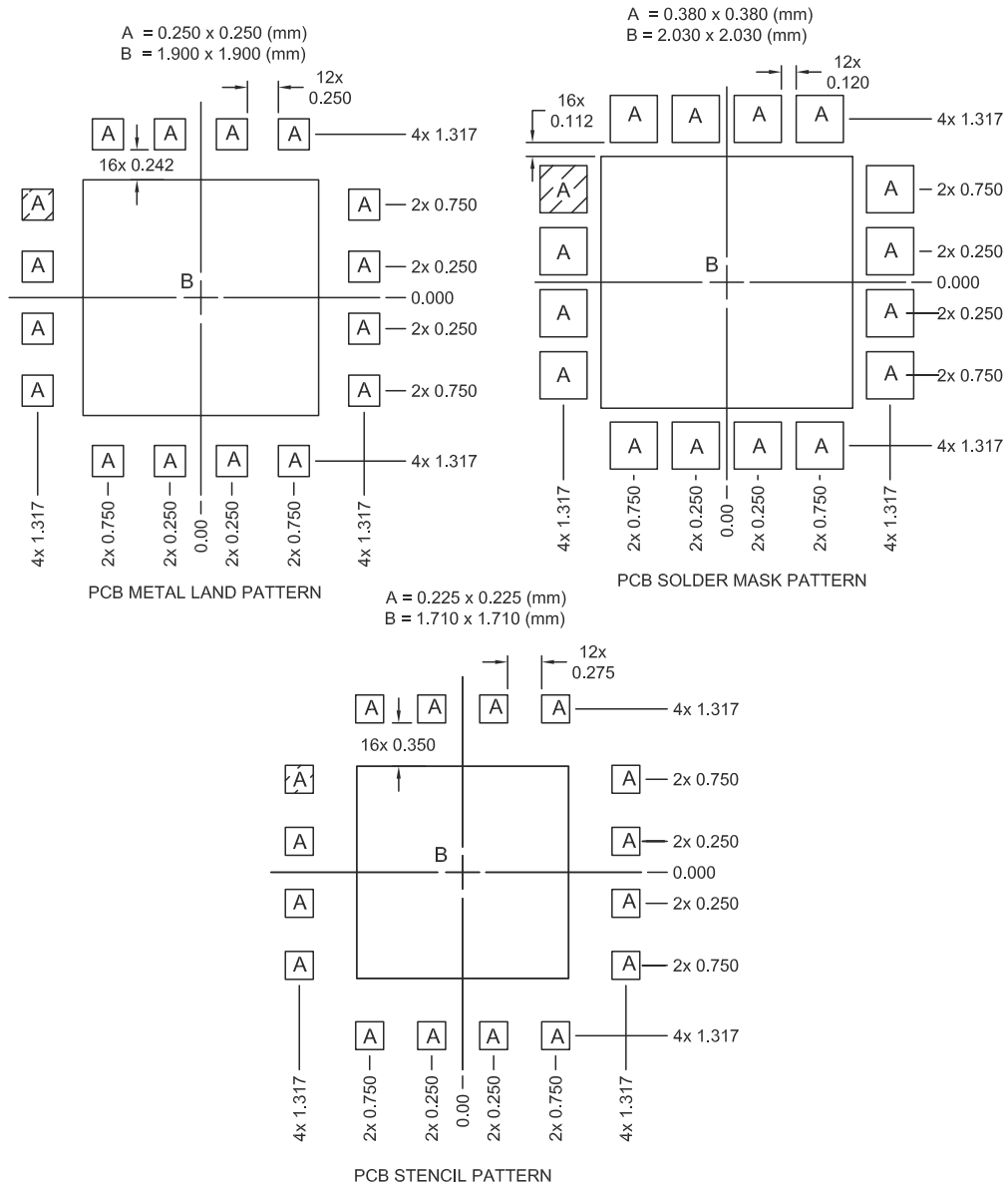
Package Drawing



NOTES:

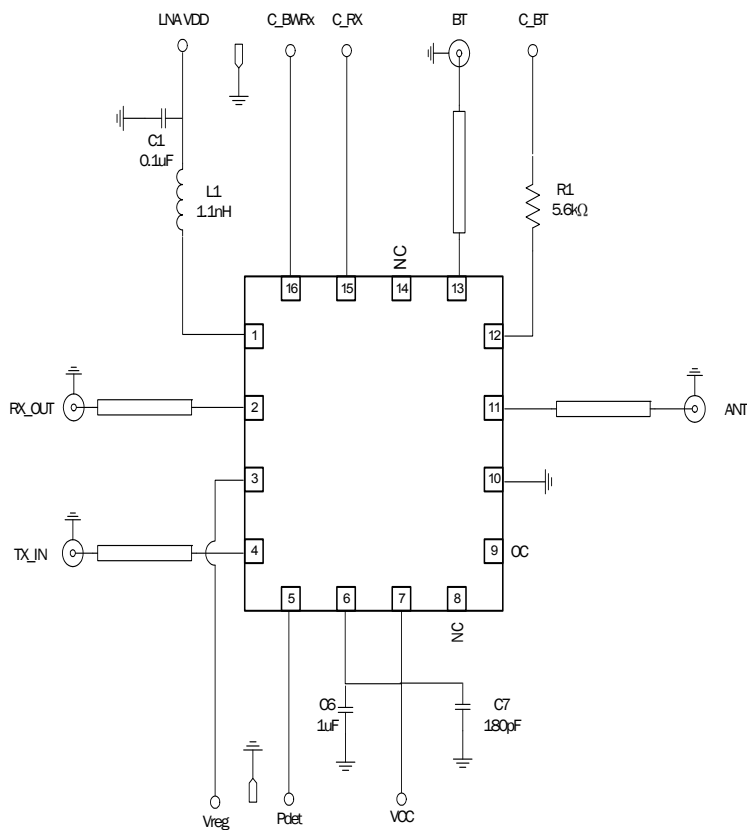
- 1 Shaded Area is Pin 1 Indicator

RF5755 PCB Footprint and Stencil Recommendations



Shaded are represents Pin 1 location.

Evaluation Board Schematic



Theory of Operation

The RF5755 Front End Module (FEM) is designed for WiFi applications in the 2.5GHz ISM band. It can be applied in many portable applications such as handsets, personal media players, and portable battery power equipment. This highly integrated module can be connected directly to the battery without additional voltage regulators.

WiFi TRANSMIT MODE

The RF5755 requires a single positive supply (V_{CC}), a positive supply for switch controls, and a regulated supply for the V_{REG} to maintain nominal bias current. The RF5755 transmit path has a typical gain of 27 dB from 2.4GHz to 2.5GHz, and delivers 20dBm typical output power under 54Mbps OFDM modulation and 23dBm under 1Mbps 11b modulation. The RF5755 contains basic filter components to produce a bandpass response for the transmit path. Due to space constraints inside the module, filtering is limited to a few resonant poles and additional filters may be required depending upon the end-user's application. While in transmit mode, the active components are the power amplifier (PA) and the Tx branch of the SP3T switch. Refer to the logic control table for proper settings.

Tx Biasing Instructions

- Connect the Tx input (pin-4) to a signal generator and a spectrum analyzer at the antenna output (pin-11).
- Set V_{CC} to 3.3V with V_{REG} set to 0V.
- Turn V_{REG} on and set voltage to 3.1V. V_{REG} controls the current drawn by the PA and it should quickly reach a quiescent current of approximately $90\text{mA} \pm 20\text{mA}$. Care must be exercised not to exceed 3.5V on the V_{REG} pin or the part may be damaged.
- Control bias to the transmit branch of the SP3T switch is tied directly to V_{REG} .
- The SP3T controls for the off branches (C_RX and C_BT) must be set to a logic "low" (0.2V max) or grounded. In the event that one of these branches is left floating or in a logic "high" the performance of the PA will degrade significantly. Likewise, unused RF ports must be terminated in 50Ω to simulate actual system conditions and prevent RF signals from coupling back to the PA.
- Turn RF on.

WiFi RECEIVE MODE

Within the frequency band of operation 2.4GHz to 2.5GHz, the RF5755 WiFi receive path has a typical gain of 16dB and a NF of 2.1dB with about 10mA of current. In Rx mode, only the Rx branch of the SP3T and the LNA are active. Refer to the logic control table for proper settings.

Rx Biasing Instructions

- Connect the Rx input (ANT/pin-11) to a signal generator and a spectrum analyzer at the Rx output (pin-2). A VNA may be used as well.
- Turn the LNA bias on (pin-1) and set the voltage to 3.3V.
- Set C_RX (pin-15) high. This turns on the receive branch of the SP3T.
- The SP3T controls for the off branches (V_{REG} and C_BT) must be set to a logic "low" (0.2V max) or grounded. In the event that one of these branches is left floating or in a logic "high" the performance will degrade. It is recommended to terminate unused RF Ports in 50Ω .
- Set the control bias for the SPST switch (C_BWRX/pin-16) "low" during WiFi Rx only mode.
- Turn RF on.

WiFi and **BLUETOOTH®** RECEIVE (SIMULTANEOUS MODE)

The RF5755 WiFi and *Bluetooth®* receive circuits were specifically designed to address issues of simultaneous operation. In this mode both signals can be received at the same time when the C_BWRX (pin-16) is set high. The typical gain for each RF path is approximately 13dB and a NF of 3dB. During simultaneous mode the active components are the LNA, the SPST switch, and only the Rx branch of the SP3T. Refer to the logic control table for proper settings.

Simultaneous Mode Biasing Instructions

- Connect the RF input (ANT/pin-11) to a signal generator and a spectrum analyzer at the RX (pin-2) and BT (pin-13) RF ports. A multiport VNA may be used as well.
- Turn the LNA bias on (pin-1) and set the voltage to 3.3V.
- Set C_RX (pin-15) and C_BWRX (pin-16) high. This turns on the receive branch of the SP3T and the SPST switch.
- The SP3T controls for the off branches (V_{REG} and C_BT) must be set to a logic “low” (0.2V max) or grounded. In the event that one of these branches is left floating or in a logic “high” the performance will degrade. It is recommended to terminate unused RF Ports in 50 Ω .
- Turn RF on.

BLUETOOTH® MODE

The RF5755 *Bluetooth®* only mode is implemented through the SP3T switch by setting C_BT “high.” Typical insertion loss is about 1.2dB.

Bluetooth® Biasing Instructions

- Connect the RF input (ANT/pin-11) to a signal generator and a spectrum analyzer at the BT (pin-13) RF port. A VNA may be used in place of the signal generator and SA.
- Set C_BT (pin-12) “high.” This turns the *Bluetooth®* branch of the SP3T switch on.
- The SP3T controls for the off branches (V_{REG} and C_RX) must be set to a logic “low” (0.2V max) or grounded. Do not leave floating.
- Terminate unused RF Ports in 50 Ω .
- Turn RF on.

APPLICATION CIRCUIT AND LAYOUT RECOMMENDATIONS

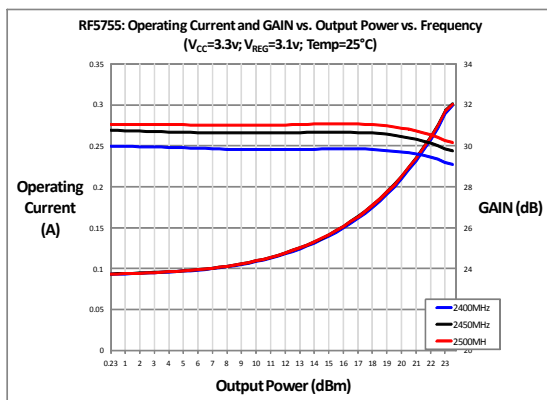
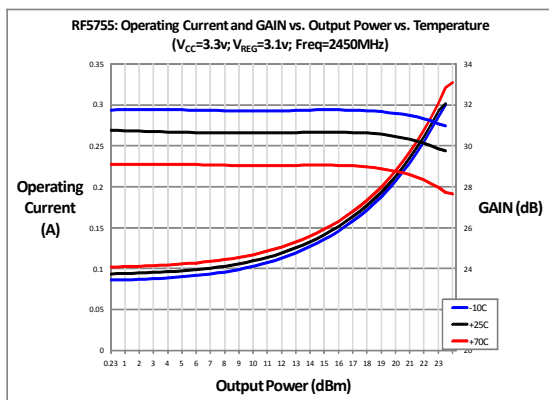
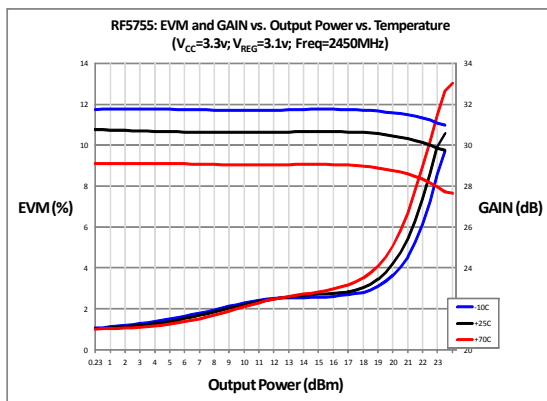
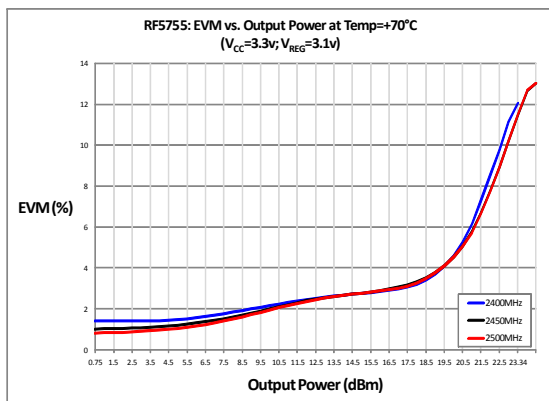
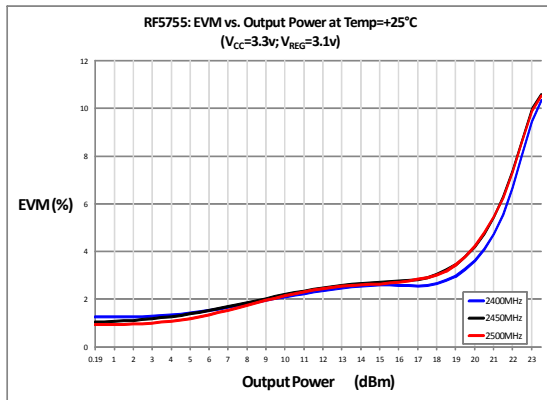
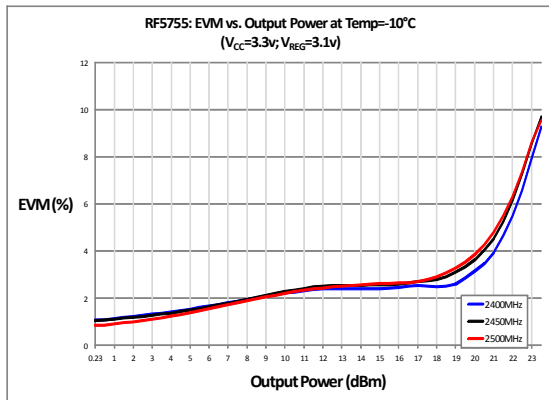
The RF5755 integrates the matching networks and DC blocking capacitors for all RF ports. This greatly reduces the number of external components and layout area needed to implement this FEM. Typically only a total of four external components are required to achieve nominal performance. However, depending on board layout and the many noise signals that could potentially couple to the RF5755, additional bypassing capacitors may be required to properly filter out unwanted signals that might degrade performance.

The LNA bias components consist of an inductor and a decoupling capacitor. The inductor value is critical to optimize NF and return loss at the Rx output. For best performance and trade off between critical parameters such as NF, Gain, and IP3, the total inductance including board trace should be approximately 1.2nH. The 5.6k Ω series resistor for the *Bluetooth®* control line helps to prevent unwanted signals from coupling to this pin. The resistor should be placed as close as possible to the package pin. The last component needed in the application circuit is a low frequency bypass capacitor on the V_{CC} line. In general, it is good RF practice to have proper decoupling of supply lines to filter out noise. Occasionally, depending on the level of coupling or parasitics of the board, a high frequency bypass capacitor must be added as well.

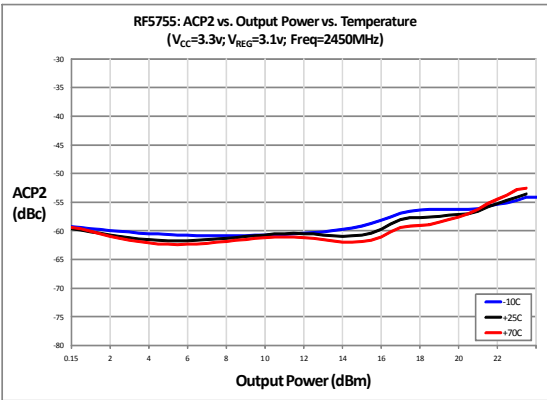
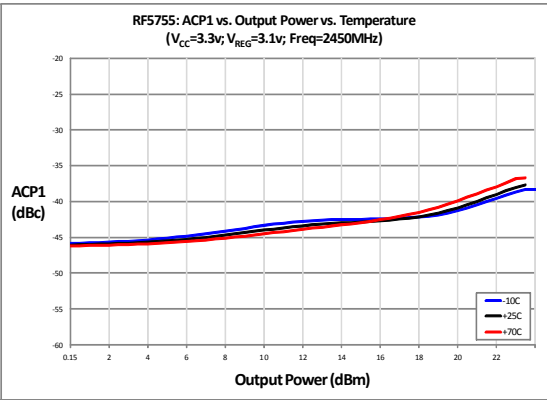
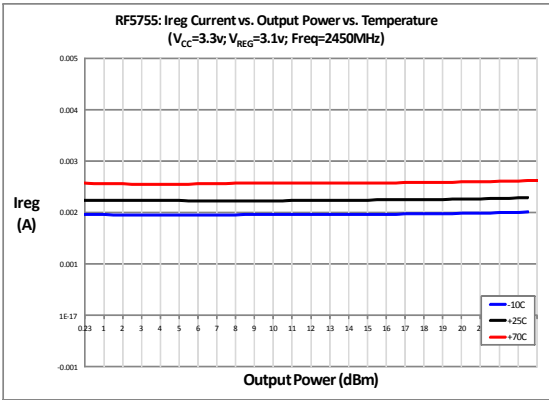
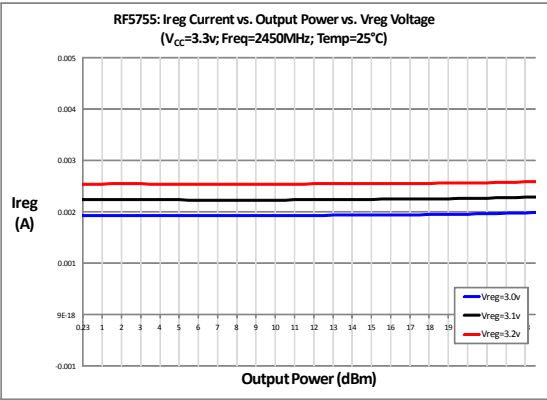
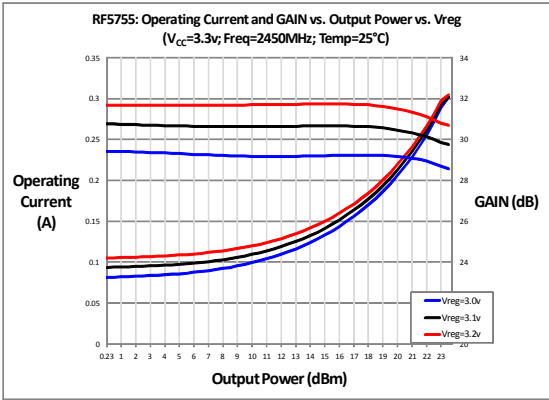
In order to optimize performance for both the Transmit and Receive paths, a good layout design must be implemented. As it is well known in the RF world, any mismatch and off port loading affects performance. To minimize this effect and have a more robust layout, all RF traces must be 50 Ω . Adequate grounding along the RF traces and on the FEM ground slug must be exer-

cised. This will minimize coupling and provide good thermal dissipation when the PA is operating at high power. For reference, the RFMD evaluation board uses 9 thermal ground vias (hole/capture pad 12/22mil) on the ground slug. Additionally, if space permitted, V_{CC} and control lines must be isolated from each other with ground vias in between them. RFMD evaluation board gerbers are available upon request.

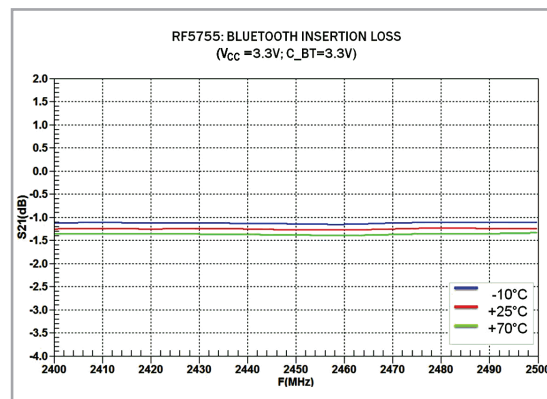
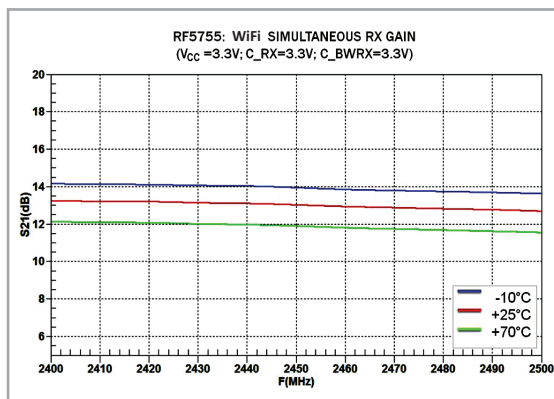
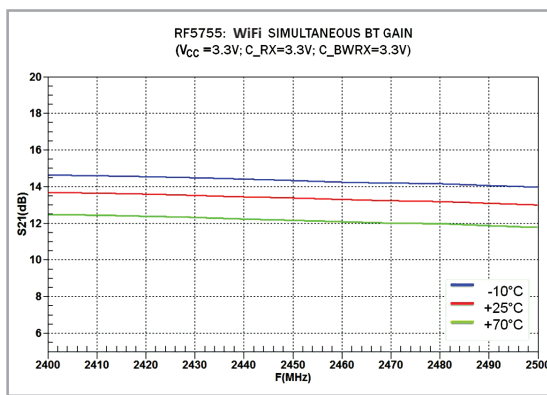
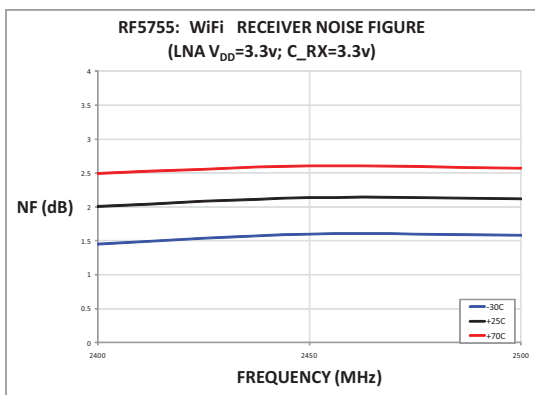
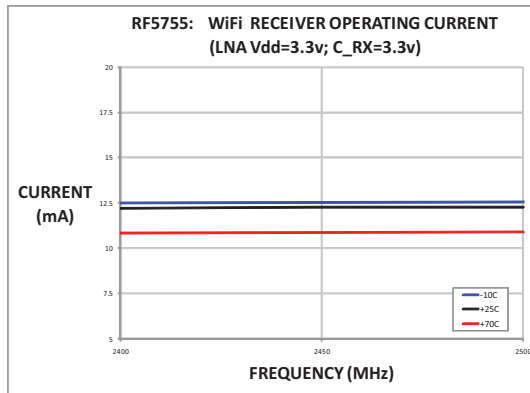
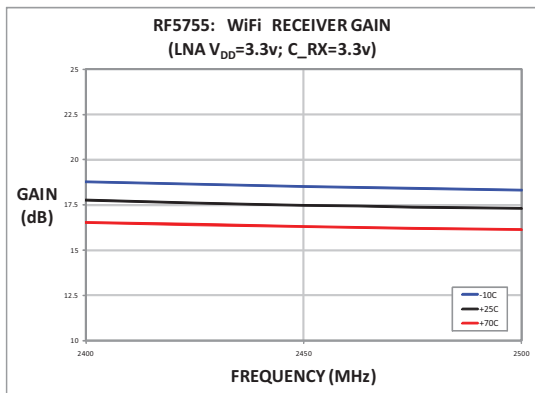
RF5755 Performance Graphs



RF5755 Performance Graphs (cont.)



RF5755 Receiver Performance Graphs



Mouser Electronics

Authorized Distributor

Click to View Pricing, Inventory, Delivery & Lifecycle Information:

[Qorvo:](#)

[RF5755TR7](#)